

# DARLINGTON ARRAYS

- EIGHT DARLINGTONS PER PACKAGE
- OUTPUT CURRENT 400 mA PER DRIVER (500mA PEAK)
- OUTPUT VOLTAGE 90 V (V<sub>CE (sus)</sub>) = 70 V)
- INTEGRAL SUPPRESSION DIODES FOR INDUCTIVE LOADS
- OUTPUTS CAN BE PARALLELED FOR HIGHER CURRENT
- TTL / CMOS INPUTS
- INPUTS PINNED OPPOSITE OUTPUTS TO SIMPLIFY LAYOUT



#### **DESCRIPTION**

The L603 and L604 are high voltage, high current darlington arrays each containing eight open collector darlington pairs with common emitters. Each channel is rated at 400mA and can with stand peak currents of 500 mA.

Suppression diodes are included for ir ductive load driving and the inputs are pirace apposite the outputs to simplify board lavour

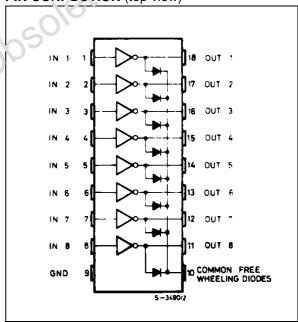
The four versions intended to all common logic families:

**L603** = 5V Ti.

**L604** = 5 15V CMOS

These versatile devices are useful for driving a vice range of loads, including solenoids, relays DC motors, LED displays, filament lamps, thermal printheads and high power buffers.

# PIN CONNECTION (top view)



#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CEX</sub>	Collector Emitter Voltage (input open)	90	V
I <sub>C</sub>	Collector Current	0.4	Α
Ic	Collector Peak Current	0.5	Α
Vi	Input Voltage (for L603 and L604)	30	V
P <sub>tot</sub>	Total Power Dissipation a T <sub>amb</sub> = 25°C	1.8	W
T <sub>op</sub>	Operating Junction Temperature	-25 to 150	°C

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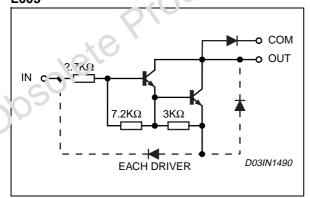
#### THERMAL DATA

	Symbol	Parameter	Value	Unit
Ī	R <sub>th-j amb</sub>	Thermal Resistance Junction ambient	max 70	°C/W

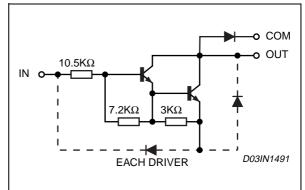
### **ELECTRICAL CHARACTERISTCS**

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I <sub>CEX</sub>	Output Leakage Current	V <sub>CE</sub> = 90V			10	μΑ
V <sub>CE(sat)</sub>	Collector Emitter Saturation Voltage	$I_C = 300 \text{mA}; I_B = 500 \mu\text{A}$			2	V
	voltage	$I_C = 200 \text{mA}; I_B = \mu \text{A}$			1.7	V
		$I_C = 100 \text{mA}; I_B = 250 \mu\text{A}$			ı 2	V
Vi	Maximum Input Voltage (ON condition)	V <sub>CE</sub> = 3V; I <sub>C</sub> = 300mA L603 L604	01	ogi	2.5 5	V V
Vi	Maximum Input Voltage (OFF condition)	V <sub>CE</sub> = 90V; I <sub>C</sub> = 25μA L603 L604	0.75			V V
I <sub>R</sub>	Clamp Diode Reverse Current	V <sub>R</sub> = 90V			50	μΑ
VF	Clamp Diode Forward Voltage	I <sub>F</sub> = 300m A		2	2.4	V
t <sub>on</sub>	Turn-on Delay	0.5 V <sub>i</sub> to 0.5 V <sub>o</sub>		0.4		μs
t <sub>off</sub>	Turn-off Delay	C.5 /i to 0.5 V <sub>o</sub>		0.4		μΑ

## L603



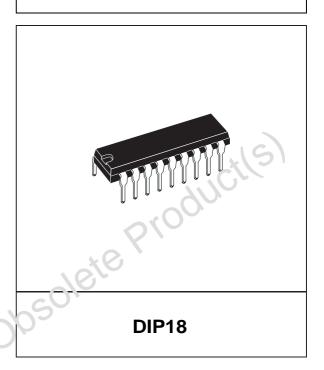
### L604

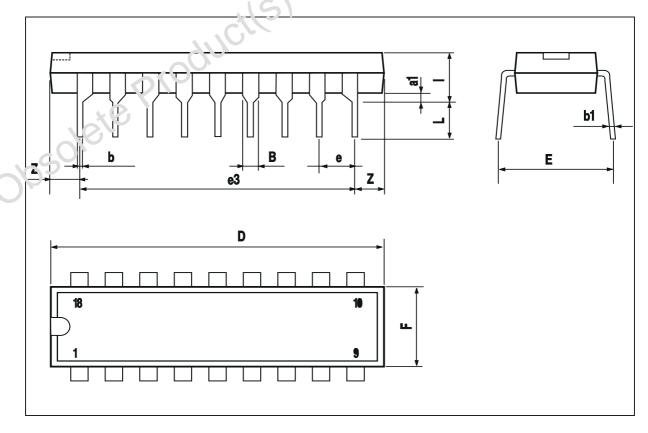


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DIM.		mm			inch	
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.254			0.010		
В	1.39		1.65	0.055		0.065
b		0.46			0.018	
b1		0.25			0.010	
D			23.24			0.915
E		8.5			0.335	
Ф		2.54			0.100	
e3		20.32			0.800	
F			7.1			0.280
1			3.93			0.155
L		3.3			0.130	
Z		1.27	1.59		0.050	0.063

# OUTLINE AND MECHANICAL DATA







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